

### **Epoxy Nonwoven Aramid**



55NT is an epoxy laminate and prepreg system, reinforced with a non-woven aramid substrate. This system combines compatibility with lead-free processing, using a high-temperature epoxy resin, with the low in-plane (X,Y) expansion and outstanding dimensional stability of non-woven aramid reinforcement.

#### Features:

- Low in-plane (X,Y) expansion of 6-9 ppm/°C allows attachment of SMT devices with minimal risk of solder joint failure due to CTE mismatch
- Nonwoven aramid organic reinforcement provides outstanding dimensional stability and enhanced registration for improved multilayer yields
- Tg of 170°C, decomposition temperature of 368°C, and Z-expansion of 3.5% between 50 -260°C ensures compatibility with most lead-free processes
- Polymeric reinforcement results in PCBs typically 25% lighter in weight than conventional glass-reinforced laminates
- Laser and plasma ablatable for high speed formation of microvias and other features as small as 25μm (μ0.001")
- Electrical and mechanical properties meeting the requirements of IPC-4101/55
- · Compatible with lead-free processing

#### **Typical Applications:**

- Military and commercial avionics, missiles and missile defense, satellites, and other highreliability SMT applications requiring low in-plane (x,y) CTE values
- Other applications requiring low in-plane (x,y) CTE values, including chip carriers and multichip modules, where the chip carrier serves as an interposer for attachment to the underlying PCB
- PCBs that are subjected to elevated temperatures during processing, such as lead-free soldering

# **55NT**

### Typical Properties:

| Property   | Units             | Value                 | Test Method         |
|--|-------------------|-----------------------|---------------------|
| Electrical Properties  |                   |                       |                     |
| Dielectric Constant @ 1 MHz                                    | -                 | 3.8                   | IPC TM-650 2.5.5.3  |
| @ 1 GHz  | -                 |                       | IPC TM-650 2.5.5.9  |
| Dissipation Factor @ 1 MHz                                     |                   | 0.015                 | IPC TM-650 2.5.5.3  |
| @ 1 GHz  |                   |                       | IPC TM-650 2.5.5.9  |
| Volume Resistivity   |                   |                       |                     |
| C96/35/90  | MΩ-cm             | 2.3 x 10 <sup>7</sup> | IPC TM-650 2.5.17.1 |
| E24/125  | MΩ-cm             | 6.6 x 10 <sup>7</sup> | IPC TM-650 2.5.17.1 |
| Surface Resistivity  |                   |                       |                     |
| C96/35/90  | MΩ                | 1.8 x 10 <sup>8</sup> | IPC TM-650 2.5.17.1 |
| E24/125  | MΩ                | 1.6 x 10 <sup>8</sup> | IPC TM-650 2.5.17.1 |
| Electrical Strength  | Volts/mil (kV/mm) | 1240 (48.8)           | IPC TM-650 2.5.6.2  |
| Dielectric Breakdown   | kV                |                       | IPC TM-650 2.5.6    |
| Arc Resistance   | sec               | 165                   | IPC TM-650 2.5.1    |
|  |                   |                       |                     |
| Thermal Properties   |                   |                       |                     |
| Glass Transition Temperature (Tg)                              |                   |                       |                     |
| TMA  | °C                |                       | IPC TM-650 2.4.24C  |
| DSC  | °C                | 170                   | IPC TM-650 2.4.25D  |
| Decomposition Temperature                                      |                   |                       |                     |
| Initial  | °C                | 351                   | IPC TM-650 2.4.24.6 |
| 5% weight loss   | °C                | 368                   | IPC TM-650 2.4.24.6 |
| T260   | min               | >60                   | IPC TM-650 2.4.24.1 |
| T288   | min               | >60                   | IPC TM-650 2.4.24.1 |
| T300   | min               | 28                    | IPC TM-650 2.4.24.1 |
| CTE (X,Y)  | ppm/°C            | 6-9                   | IPC TM-650 2.4.41   |
| CTE (Z)  |                   |                       |                     |
| < Tg   | ppm/°C            | 99                    | IPC TM-650 2.4.24C  |
| > Tg   | ppm/°C            | 259                   | IPC TM-650 2.4.24C  |
| z-axis Expansion (50-260°C)                                    | %                 | 3.5                   | IPC TM-650 2.4.24C  |
| Mechanical Properties  |                   |                       |                     |
| Peel Strength to Copper (1 oz/35 micron)                       |                   |                       |                     |
| After Thermal Stress   | lb./in (N/mm)     | 3.6 (0.6)             | IPC TM-650 2.4.8C   |
| At Elevated Temperatures                                       | lb./in (N/mm)     | 3.6 (0.6)             | IPC TM-650 2.4.8.2A |
| After Process Solutions  | lb./in (N/mm)     | 3.6 (0.6)             | IPC TM-650 2.4.8C   |
| Young's Modulus CD/MD  | Mpsi (GPa)        | 2.0 ( 13.8)           | ASTM E111           |
| Flexural Strength  | kpsi (MPa)        | 38 (262)              | ASTM D3039          |
| Tensile Strength CD/MD   | kpsi (MPa)        | 5 (35)                | ASTM D3039          |
| Poisson's Ratio  | -                 | - (,                  | ASTM E13204         |
| Physical Properties  |                   |                       |                     |
| Water Absorption (0.062")                                      | %                 | 0.3                   | IPC TM-650 2.6.2.1A |
| Density  | g/cm <sup>3</sup> | 1.38                  | ASTM D792 Method A  |
| Thermal Conductivity   | W/mK              | 0.2                   | ASTM E1461          |
| Flammability   | class             | V-0                   | UL-94               |
| Results listed above are typical properties provided without w |                   |                       |                     |

Results listed above are typical properties, provided without warranty, expressed or implied, and without liability. Properties may vary, depending on design and application.

Arion reserves the right to change or update these values.

## **55NT**

#### Availability:

| Arlon<br>Part Number | Glass Style | Resin (%) | Mil/Ply | Flow % |
|----------------------|-------------|-----------|---------|--------|
| 55NT147              | E210        | 49        | 1.7     | 12     |
| 55NT247              | E220        | 49        | 2.9     | 12     |
| 55NT347              | E230        | 49        | 3.8     | 12     |
| 55NT153              | E210        | 53        | 1.8     | 15     |
| 55NT253              | E220        | 53        | 3.1     | 15     |
| 55NT353              | E230        | 53        | 4.1     | 15     |

#### **Recommended Process Conditions:**

Process inner-layers through develop, etch, and strip using standard industry practices. Use brown oxide on finner layers. Adjust dwell time in the oxide bath to ensure uniform coating. Bake inner layers in a rack for 60 minutes at 107°C - 121°C (225°F - 250°F) immediately prior to lay-up. Vacuum desiccate the prepreg for 8 - 12 hours prior to lamination.

#### Lamination Cycle:

- 1) Pre-vacuum for 30 45 minutes
- 2) Control the heat rise to 4.5°C 6.5°C (8°F 12°F) per minute between 100°C and 150°C (210°F and 300°F). Vacuum lamination is preferred. Start point vacuum lamination pressures are shownin the table below:

| Panel Size |           | Pressure |        |  |
|------------|-----------|----------|--------|--|
| in.        | mm        | psi      | kg/cm2 |  |
| 12 x 18    | 305 x 457 | 275      | 19     |  |
| 16 x 18    | 406 x 457 | 350      | 25     |  |
| 18 x 24    | 457 x 610 | 400      | 27     |  |

- 3) Product temperature at start of cure = 182°C (360°F)
- 4) Cure time at temperature = 90 minutes
- 5) Cool down under pressure at  $\leq$  6°C/min (10°F/min)

De-smear using alkaline permanganate or plasma with settings appropriate for polyimide; plasma is preferred for positive etchback

Conventional plating processes are compatible with 55NT

Standard profiling parameters may be used; chip breaker style router bits are not recommended Bake for 1 - 2 hours at 250°F (121°C) prior to solder to reflow of HASL



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For samples, technical assistance and customer service, please contact Arlon Electronic Materials at the following locations:

#### **NORTH AMERICA:**

Arlon EMD, 9433 Hyssop Drive, Rancho Cucamonga, CA Tel: (909) 987-9533 • Fax: (909) 987-8541

#### FRANCE:

CCI Eurolam 9, rue Marcelin Bertholet 92160 Antony, France

Phone: (33) 146744747 Fax: (33) 146666313

#### **GERMANY:**

CCI Eurolam Otto-Hahn-Str. 46 63303 Dreiech Germany

Phone: (49) 610339920 Fax: (49) 6103399229

#### UK & SCANDINAVIA:

CCI Eurolam – UK Ulness Walton Lane Leyland, PR26 8NB, UK

Phone: (44) 1772452236 Fax: (44) 1772456859

#### **ISRAEL:**

Tech Knowledge, Ltd. 159 Yigal Alon Street, Tel Aviv 6744367, Israel

Phone: (972) 36958117 Fax: (972) 36917117

#### **ITALY:**

Phone: (39) 025460507 Fax: (39) 0255013199

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#### SINGAPORE:

C.T.S. Industries Pte Ltd 47 Kaki Bukit Place Singapore 416225

Phone: (65) 6276 3328 Fax: (65) 6276 3336

#### **JAPAN:**

Nakao Corp. 12-8 Nihonbashi Hisamatsu-Cho Tokyo 103-0005 Japan

Phone: (81) 336623201 Fax: (81) 336617118

#### **KOREA**

UniMicrotek Co. Ltd. 478 Baekbeom-Ro, Bupyeong-Gu Incheon, Korea

Phone: (82) 32-424-1776 Fax: (82) 505-720-1785

#### CHINA:

Zack Peng Room 6A, Unit 2, Bldg 2 Jin Cheng Shi Dai, Tian Road Shenzhen, China 518103

Phone: (86) 75528236491 Fax: (86) 75528236463

#### INDIA:

Synertec 301 Raheja Chambers,12 Museum Rd Bangalore, India 560001

Phone: (91) 80-25585432 Fax: (91) 80-25588565